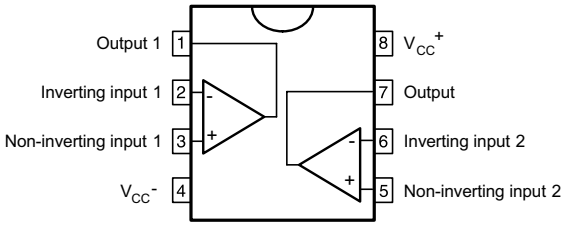
TS512, TS512A, TS512B

Precision dual operational amplifiers

Datasheet - production data

D
SO-8
(plastic micropackage)

Pin connections
(top view)



Description

The TS512x devices are high-performance dual operational amplifiers with frequency and phase compensation built into the chip. The internal phase compensation allows stable operation in voltage follower configurations in spite of its high gain bandwidth product.

The circuit presents very stable electrical characteristics over the entire supply voltage range and it is particularly intended for professional and telecom applications (such as active filtering).

The TS512B is guaranteed with a higher minimum slew rate (1.072 V/µs) than TS512 and TS512A (0.8 V/µs).

Features

- Low input offset voltage: 500 µV max. (A version)
- Low power consumption
- Short-circuit protection
- Wide power supply range:
  - Single supply: 3 to 30 V
  - Dual supplies: ±1.5 to ±15 V
- Low distortion, low noise
- High gain bandwidth product: 3 MHz
- High channel separation
- ESD protection 2 kV
- Macromodel included in this specification

This is information on a product in full production. www.st.com

Contents

1 Absolute maximum ratings and operating conditions 3

2 Schematic diagram 4

3 Electrical characteristics 5

4 Macromodel 11

4.1 Important notes concerning this macromodel 11

4.2 Macromodel code 11

5 Package information 14

6 Ordering information 16

7 Revision history 17

1 Absolute maximum ratings and operating conditions

Table 1. Absolute maximum ratings

Symbol	Parameter	Value	Unit
V_{CC}	Supply voltage	±18	V
V_{in}	Input voltage	$\pm V_{CC}$	
V_{id}	Differential input voltage	$\pm(V_{CC} - 1)$	
R_{thja}	Thermal resistance junction-to-ambient(1)	125	°C/W
R_{thjc}	Thermal resistance junction-to-case(1)	40	°C/W
T_j	Junction temperature	+150	°C
T_{stg}	Storage temperature range	-65 to +150	°C
ESD	HBM: human body model(2)	2	kV
	MM: machine model(3)	200	V
	CDM: charged device model(4)	1.5	kV

1. Short-circuits can cause excessive heating and destructive dissipation. R_{th} are typical values.
2. Human body model: a 100 pF capacitor is charged to the specified voltage, then discharged through a 1.5 kΩ resistor between two pins of the device. This is done for all couples of connected pin combinations while the other pins are floating.
3. Machine model: a 200 pF capacitor is charged to the specified voltage, then discharged directly between two pins of the device with no external series resistor (internal resistor < 5 Ω). This is done for all couples of connected pin combinations while the other pins are floating.
4. Charged device model: all pins and the package are charged together to the specified voltage and then discharged directly to ground through only one pin. This is done for all pins.

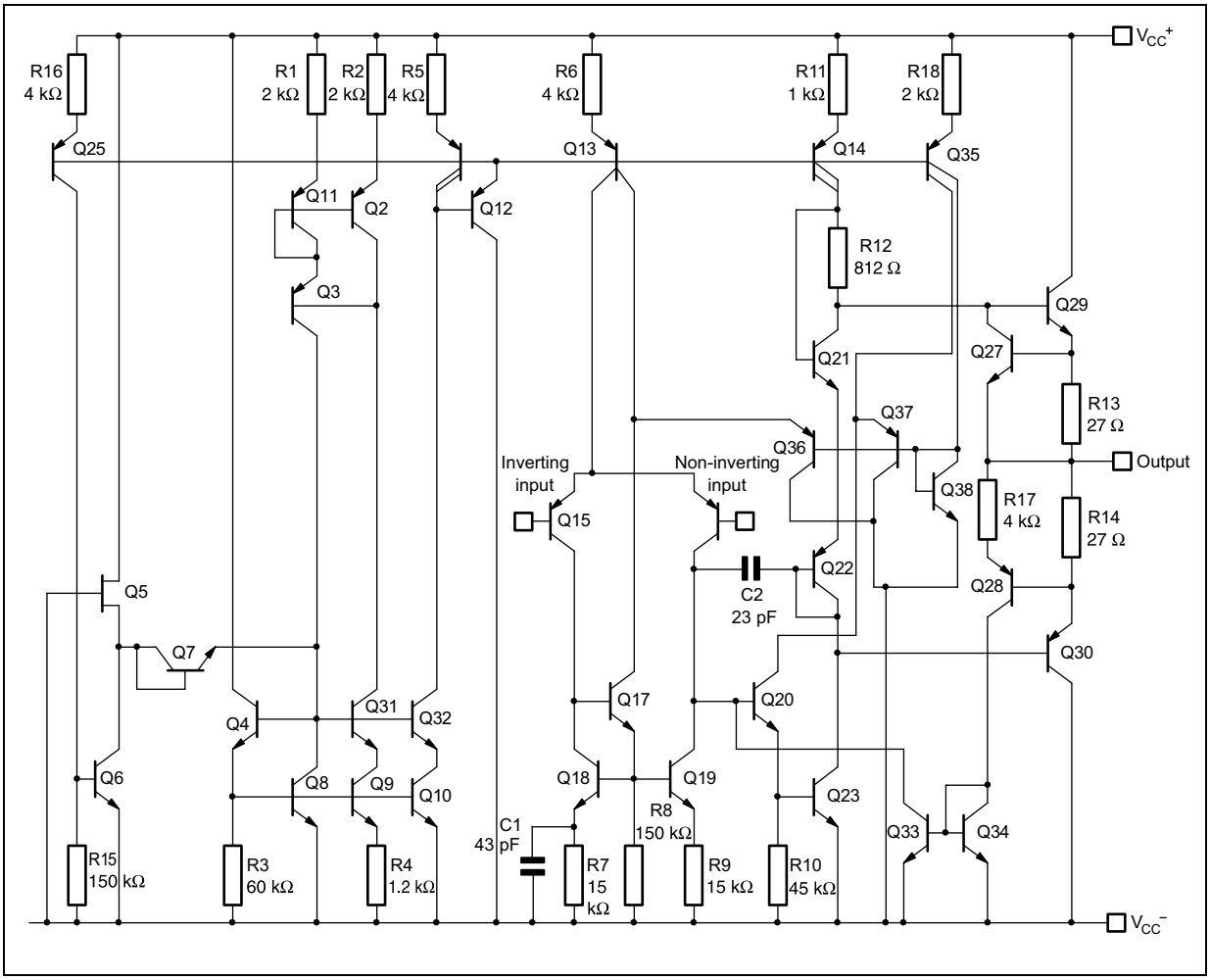
Table 2. Operating conditions

Symbol	Parameter	Value	Unit
V_{CC}	Supply voltage(1)	6 to 30V	V
V_{icm}	Common mode input voltage range	V_{CC-}+1.5 to V_{CC+}-1.5	V
T_{oper}	Operating free air temperature range	-40 to +125	°C

1. Value with respect to V_{CC-} pin.

2 Schematic diagram

Figure 1. Schematic diagram (1/2 TS512)



3 Electrical characteristics

Table 3. V_{CC} = ±15 V, T_{amb} = 25 °C (unless otherwise specified)

Symbol	Parameter	Min.	Typ.	Max.	Unit
I_{CC}	Supply current (per channel) $T_{min} \leq T_{amb} \leq T_{max}$		0.5	0.6 0.75	mA
I_{ib}	Input bias current $T_{min} \leq T_{amb} \leq T_{max}$		50	150 300	nA
R_{in}	Input resistance, f = 1 kHz		1		MΩ
V_{io}	Input offset voltage TS512 TS512A and TS512B $T_{min} \leq T_{amb} \leq T_{max}$ TS512 TS512A and TS512B		0.5	2.5 0.5 3.5 1.5	mV
ΔV_{io}	Input offset voltage drift $T_{min} \leq T_{amb} \leq T_{max}$		2		µV/°C
I_{io}	Input offset current $T_{min} \leq T_{amb} \leq T_{max}$		5	20 40	nA
ΔI_{io}	Input offset current drift $T_{min} \leq T_{amb} \leq T_{max}$		0.08		nA/°C
I_{os}	Output short-circuit current		23		mA
A_{vd}	Large signal voltage gain R_L = 2 kΩ, V_{CC} = ±15 V, $T_{min} \leq T_{amb} \leq T_{max}$ V_{CC} = ± 4 V	90	100 95		dB
GBP	Gain bandwidth product, f = 100 kHz	1.8	3		MHz
e_n	Equivalent input noise voltage, f = 1 kHz Rs = 50 Ω Rs = 1 kΩ Rs = 10 kΩ		8 10 18		$\frac{nV}{\sqrt{Hz}}$
THD	Total harmonic distortion Av = 20 dB, R_L = 2 kΩ V_o = 2 V_{pp}, f = 1 kHz		0.03		%
$\pm V_{opp}$	Output voltage swing R_L = 2 kΩ, V_{CC} = ±15 V, $T_{min} \leq T_{amb} \leq T_{max}$ V_{CC} = ± 4 V	±13	 ±3		V
V_{opp}	Large signal voltage swing R_L = 10 kΩ, f = 10 kHz		28		V_{pp}
SR	Slew rate Unity gain, R_L = 2 kΩ , TS512 and TS512A	0.8	1.5		V/µs
	Slew rate Unity gain, R_L = 2 kΩ, TS512B	1.072			
CMR	Common mode rejection ratio CMR = 20 log ($\Delta V_{ic}/\Delta V_{io}$) ($V_{ic}$ = -10 V to 10 V, Vout = V_{CC}/2, R_L > 1 MΩ)	90			dB

Table 3. V_{CC} = ±15 V, T_{amb} = 25 °C (unless otherwise specified) (continued)

Symbol	Parameter	Min.	Typ.	Max.	Unit
SVR	Supply voltage rejection ratio 20 log ($\Delta V_{CC}/\Delta V_{io}$) ($V_{CC}$ = ±4 V to ±15 V, V_{out} = V_{icm} = V_{CC}/2)	90			dB
V_{o1}/V_{o2}	Channel separation, f = 1 kHz		120		dB

Figure 2. V_{io} distribution at V_{CC} = ±15 V and T = 25 °C

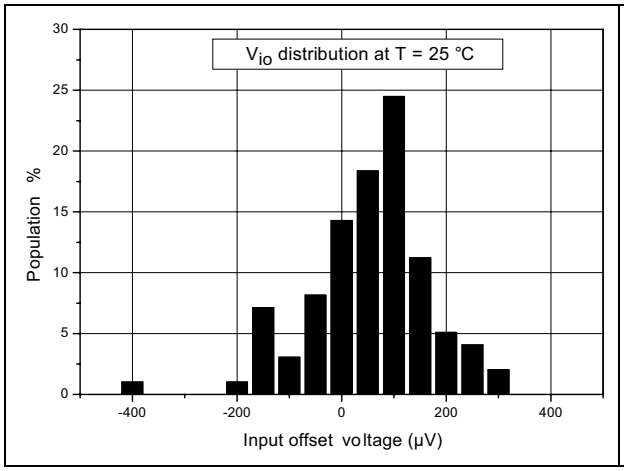


Figure 3. V_{io} distribution at V_{CC} = ±15 V and T = 125 °C

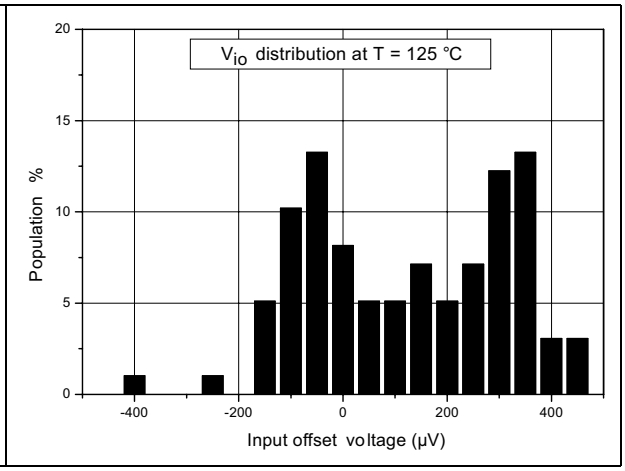


Figure 4. Input offset voltage vs. input common mode voltage at V_{CC} =10 V

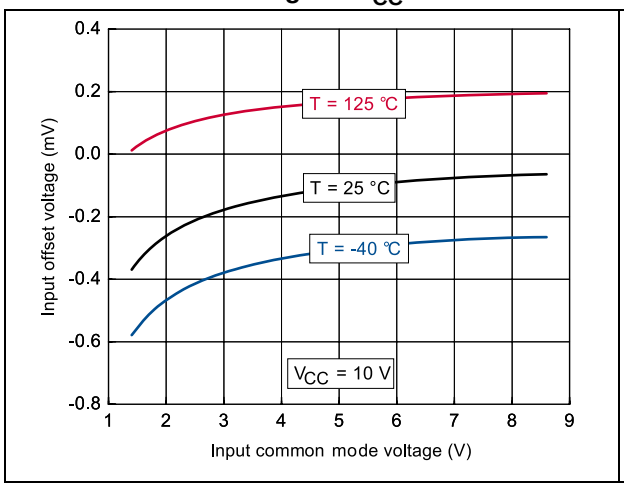


Figure 5. Input offset voltage vs. input common mode voltage at V_{CC} = 30 V

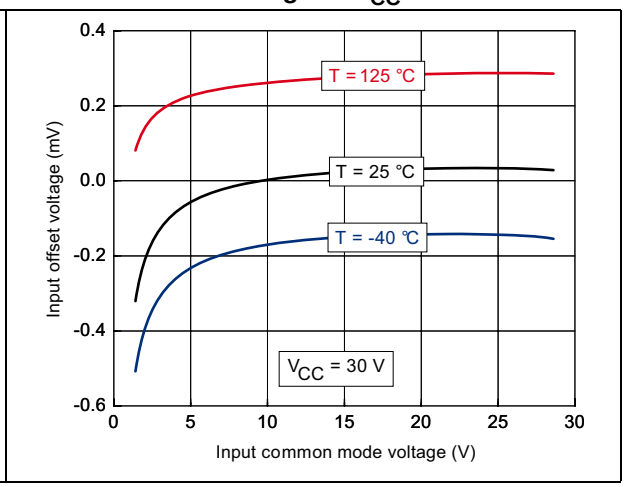


Figure 6. Supply current (per channel) vs. supply voltage at $V_{icm} = V_{CC}/2$

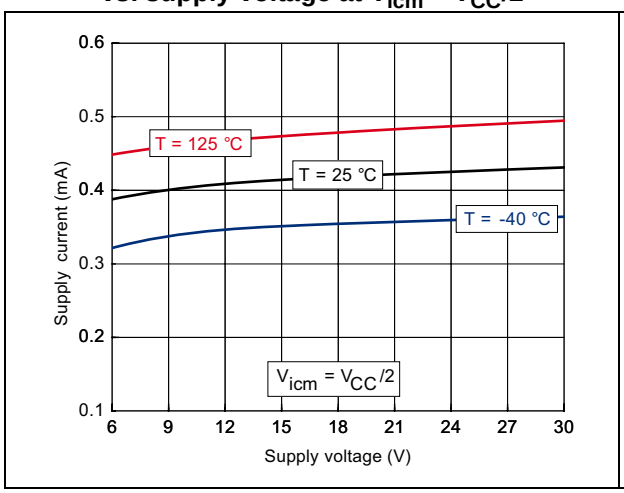


Figure 7. Supply current (per channel) vs. input common mode voltage at V_{CC} = 6 V

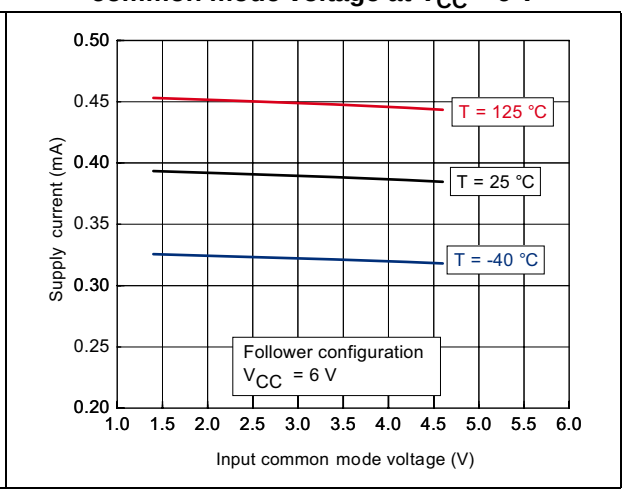


Figure 8. Supply current (per channel) vs. input common mode voltage at V_{CC} = 10 V

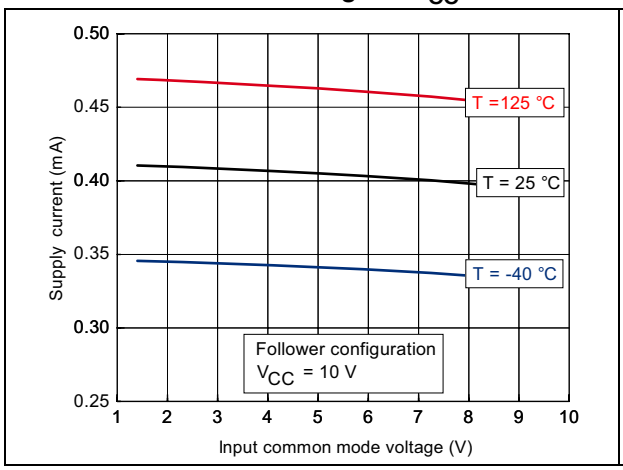


Figure 9. Supply current (per channel) vs. input common mode voltage at V_{CC} = 30 V

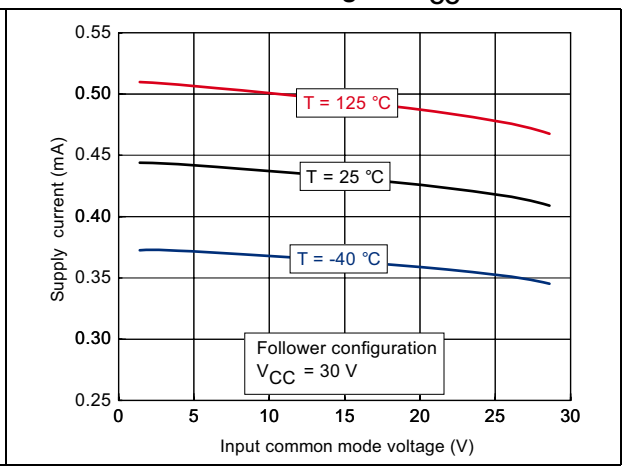


Figure 10. Output current vs. supply voltage at $V_{icm} = V_{CC}/2$

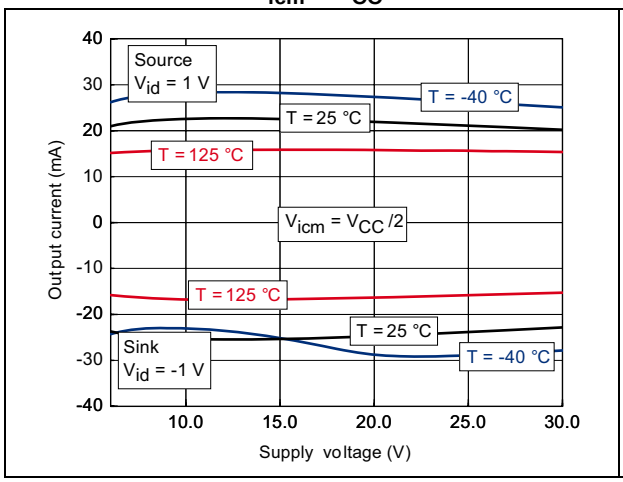


Figure 11. Output current vs. output voltage at V_{CC} = 5 V

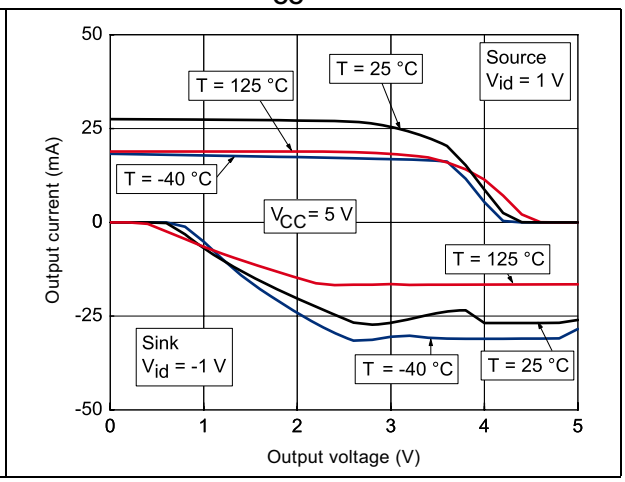


Figure 12. Output current vs. output voltage at V_{CC} = 30 V

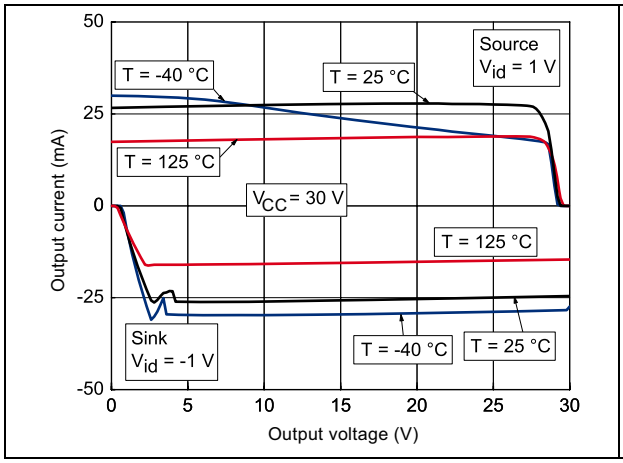


Figure 13. Voltage gain and phase for different capacitive loads at V_{CC} = 6 V, V_{icm} = 3 V and T = 25 °C

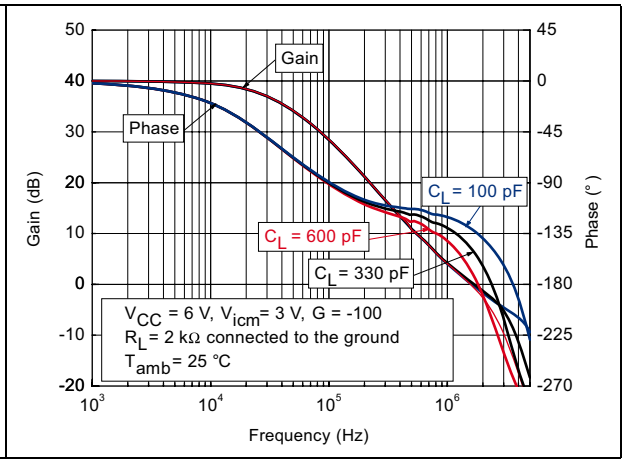


Figure 14. Voltage gain and phase for different capacitive loads at V_{CC} = 10 V, V_{icm} = 5 V and T = 25 °C

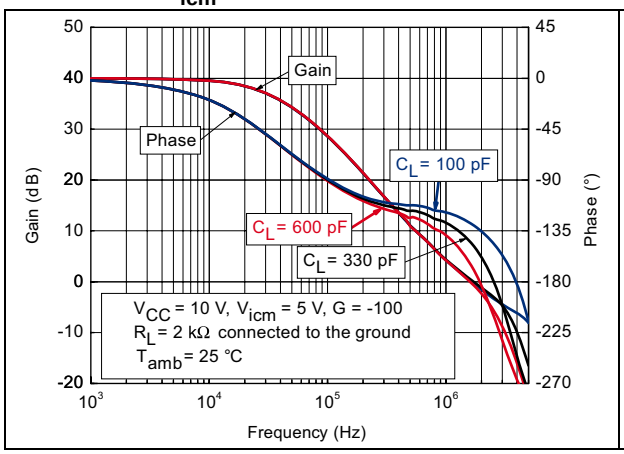


Figure 15. Voltage gain and phase for different capacitive loads at V_{CC} = 30 V, V_{icm} = 15 V and T = 25 °C

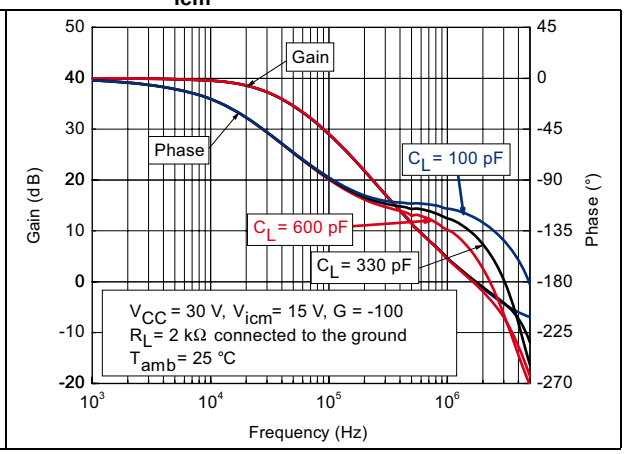


Figure 16. Frequency response for different capacitive loads at V_{CC} = 6 V, V_{icm} = 3 V and T = 25 °C

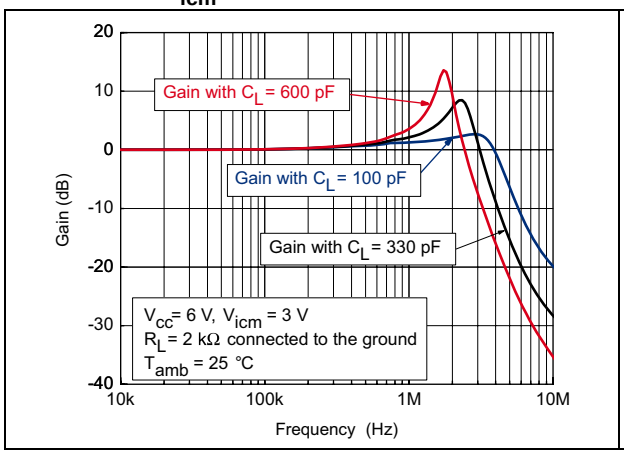


Figure 17. Frequency response for different capacitive loads at V_{CC} = 10 V, V_{icm} = 5 V and T = 25 °C

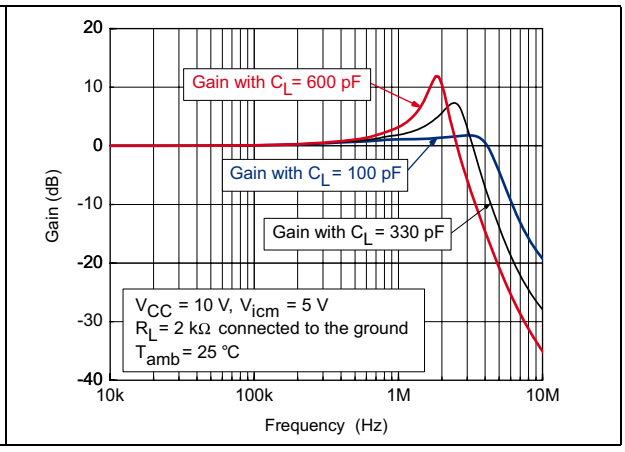


Figure 18. Frequency response for different capacitive loads at V_{CC} = 30 V, V_{icm} = 15 V and T = 25 °C

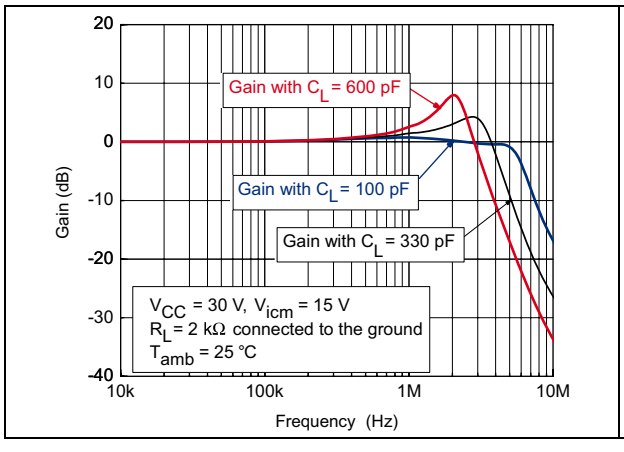


Figure 19. Phase margin vs. output current, at V_{CC} = 6 V, V_{icm} = 3 V and T = 25 °C

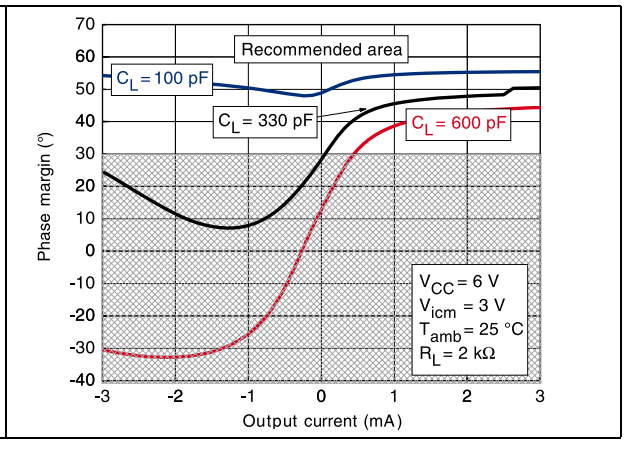


Figure 20. Phase margin vs. output current, at V_{CC} = 10 V, V_{icm} = 5 V and T = 25 °C

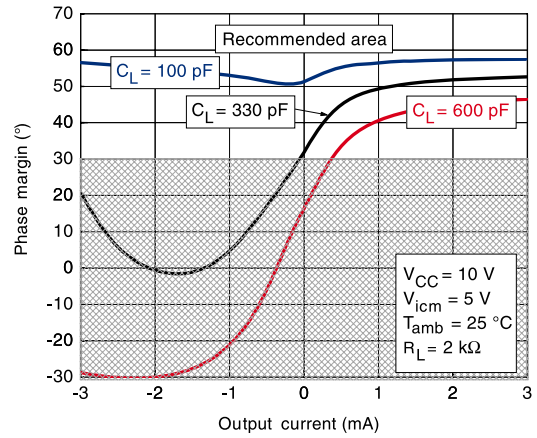
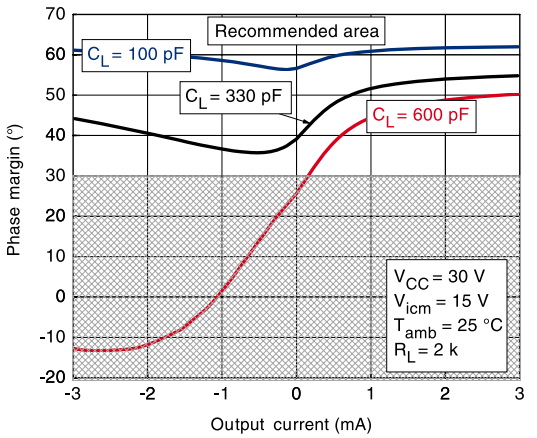


Figure 21. Phase margin vs. output current, at V_{CC} = 30 V, V_{icm} = 15 V and T = 25 °C



4 Macromodel

4.1 Important notes concerning this macromodel

- All models are a trade-off between accuracy and complexity (i.e. simulation time).
- Macromodels are not a substitute to breadboarding; rather, they confirm the validity of a design approach and help to select surrounding component values.
- A macromodel emulates the **nominal** performance of a **typical** device within **specified operating conditions** (temperature, supply voltage, for example). Thus the macromodel is often not as exhaustive as the datasheet, its purpose is to illustrate the main parameters of the product.

Data derived from macromodels used outside of the specified conditions (V_{CC}, temperature, for example) or even worse, outside of the device operating conditions (V_{CC}, V_{icm}, for example), is not reliable in any way.

4.2 Macromodel code

```
** Standard Linear Ics Macromodels, 1993.
** CONNECTIONS :
* 1 INVERTING INPUT
* 2 NON-INVERTING INPUT
* 3 OUTPUT
* 4 POSITIVE POWER SUPPLY
* 5 NEGATIVE POWER SUPPLY

.SUBCKT TS512 1 3 2 4 5
*******************************************************
.MODEL MDTH D IS=1E-8 KF=6.565195E-17 CJO=10F
* INPUT STAGE
CIP 2 5 1.000000E-12
CIN 1 5 1.000000E-12
EIP 10 5 2 5 1
EIN 16 5 1 5 1
RIP 10 11 2.600000E+01
RIN 15 16 2.600000E+01
RIS 11 15 1.061852E+02
DIP 11 12 MDTH 400E-12
DIN 15 14 MDTH 400E-12
VOFP 12 13 DC 0
VOFN 13 14 DC 0
IPOL 13 5 1.000000E-05
CPS 11 15 12.47E-10
DINN 17 13 MDTH 400E-12
VIN 17 5 1.500000e+00
DINR 15 18 MDTH 400E-12
```

```
VIP 4 18 1.500000E+00
FCP 4 5 VOFP 3.400000E+01
FCN 5 4 VOFN 3.400000E+01
FIBP 2 5 VOFN 1.000000E-02
FIBN 5 1 VOFP 1.000000E-02
* AMPLIFYING STAGE
FIP 5 19 VOFP 9.000000E+02
FIN 5 19 VOFN 9.000000E+02
RG1 19 5 1.727221E+06
RG2 19 4 1.727221E+06
CC 19 5 6.000000E-09
DOPM 19 22 MDTH 400E-12
DONM 21 19 MDTH 400E-12
HOPM 22 28 VOUT 6.521739E+03
VIPM 28 4 1.500000E+02
HONM 21 27 VOUT 6.521739E+03
VINM 5 27 1.500000E+02
GCOMP 5 4 4 5 6.485084E-04
RPM1 5 80 1E+06
RPM2 4 80 1E+06
GAVPH 5 82 19 80 2.59E-03
RAVPHGH 82 4 771
RAVPHGB 82 5 771
RAVPHDH 82 83 1000
RAVPHDB 82 84 1000
CAVPHH 4 83 0.331E-09
CAVPHB 5 84 0.331E-09
EOUT 26 23 82 5 1
VOUT 23 5 0
ROUT 26 3 6.498455E+01
COUT 3 5 1.000000E-12
DOP 19 25 MDTH 400E-12
VOP 4 25 1.742230E+00
DON 24 19 MDTH 400E-12
VON 24 5 1.742230E+00
.ENDS
```

Table 4. V_{CC} = ±15 V, T_{amb} = 25 °C (unless otherwise specified)

Symbol	Conditions	Value	Unit
V_{io}		0	mV
A_{vd}	R_L = 2 kΩ	100	V/mV
I_{CC}	No load, per channel	350	µA
V_{icm}		-13.4 to 14	V
V_{OH}	R_L = 2 kΩ	+14	V
V_{OL}	R_L = 2 kΩ	-14	V
I_{sink}	V_o = 0 V	27.5	mA
I_{source}	V_o = 0 V	27.5	mA
GBP	R_L = 2 kΩ, C_L = 100 pF	2.5	MHz
SR	R_L = 2 kΩ	1.4	V/µs
∅m	R_L = 2 kΩ, C_L = 100 pF	55	Degrees

5 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK specifications, grade definitions and product status are available at: *www.st.com*. ECOPACK is an ST trademark.

Figure 22. SO-8 package outline

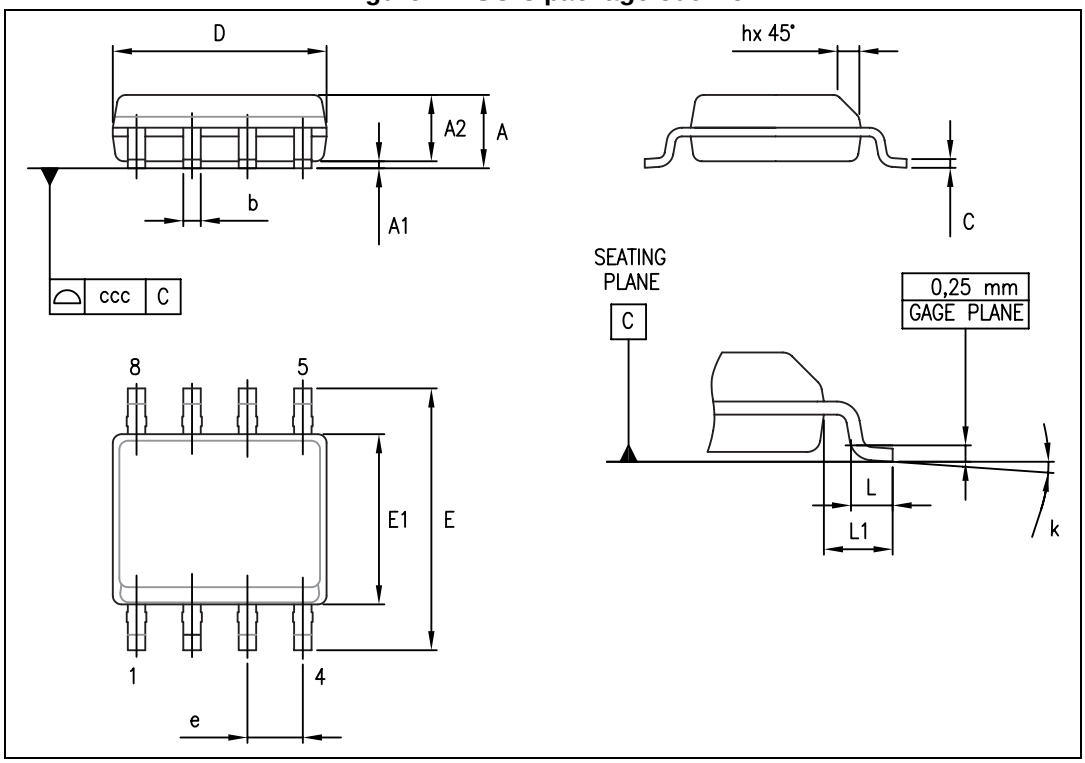


Table 5. SO-8 package mechanical data

Symbol	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A			1.75			0.069
A1	0.10		0.25	0.004		0.010
A2	1.25			0.049		
b	0.28		0.48	0.011		0.019
c	0.17		0.23	0.007		0.010
D	4.80	4.90	5.00	0.189	0.193	0.197
E	5.80	6.00	6.20	0.228	0.236	0.244
E1	3.80	3.90	4.00	0.150	0.154	0.157
e		1.27			0.050	
h	0.25		0.50	0.010		0.020
L	0.40		1.27	0.016		0.050
L1		1.04			0.040	
k	0		8°	1°		8°
ccc			0.10			0.004

6 Ordering information

Table 6. Order codes

Order code	Temperature range	Package	Packaging	Marking
TS512IDT	-40 °C, + 125 °C	SO-8	Tape and reel	512I
TS512AIDT				512AI
TS512IYDT(1)		SO-8 (automotive grade)		512IY
TS512AIYDT(1)				512AIY
TS512BIYDT(1)				512BIY

1. Qualification and characterization according to AEC Q100 and Q003 or equivalent, advanced screening according to AEC Q001 and Q002 or equivalent.

7 Revision history

Table 7. Document revision history

Date	Revision	Changes
21-Nov-2001	1	Initial release.
23-Jun-2005	2	PPAP references inserted in the datasheet, see Table 6: Order codes.
05-May-2008	3	AC and DC performance characteristics curves added for V_{CC}= 6V, V_{CC}= 10V and V_{CC}= 30V. Modified I_{CC} typ, added parameters over temperature range in electrical characteristics table. Corrected macromodel information.
04-Feb-2010	4	Updated document format. Added TS512A and related parameters. Modified footnote 1 under Table 2. Removed Figure 11. Modified Figure 12 and Figure 13. Removed TS512AIYD order code from Table 6.
12-Sep-2012	5	Updated CMR and SVR test conditions inTable 3. Removed TS512IYD order code from Table 6. Minor corrections throughout document.
20-Mar-2014	6	Removed DIP8 package option Removed shipping option in tubes from Table 6: Order codes Updated footnote 1 of Table 6: Order codes Minor textual updates
17-Apr-2017	7	Updated title, Features, Description and Table 6: Order codes to add the TS512B device and related parameters.
15-May-2017	8	Updated title, added reference to TS512B device in *Table 3* Vio parameter description.

IMPORTANT NOTICE – PLEASE READ CAREFULLY

STMicroelectronics NV and its subsidiaries (“ST”) reserve the right to make changes, corrections, enhancements, modifications, and improvements to ST products and/or to this document at any time without notice. Purchasers should obtain the latest relevant information on ST products before placing orders. ST products are sold pursuant to ST’s terms and conditions of sale in place at the time of order acknowledgement.

Purchasers are solely responsible for the choice, selection, and use of ST products and ST assumes no liability for application assistance or the design of Purchasers’ products.

No license, express or implied, to any intellectual property right is granted by ST herein.

Resale of ST products with provisions different from the information set forth herein shall void any warranty granted by ST for such product.

ST and the ST logo are trademarks of ST. All other product or service names are the property of their respective owners.

Information in this document supersedes and replaces information previously supplied in any prior versions of this document.

© 2017 STMicroelectronics – All rights reserved

Стандарт Электрон Связь

Мы молодая и активно развивающаяся компания в области поставок электронных компонентов. Мы поставляем электронные компоненты отечественного и импортного производства напрямую от производителей и с крупнейших складов мира.

Благодаря сотрудничеству с мировыми поставщиками мы осуществляем комплексные и плановые поставки широчайшего спектра электронных компонентов.

Собственная эффективная логистика и склад в обеспечивает надежную поставку продукции в точно указанные сроки по всей России.

Мы осуществляем техническую поддержку нашим клиентам и предпродажную проверку качества продукции. На все поставляемые продукты мы предоставляем гарантию .

Осуществляем поставки продукции под контролем ВП МО РФ на предприятия военно-промышленного комплекса России , а также работаем в рамках 275 ФЗ с открытием отдельных счетов в уполномоченном банке. Система менеджмента качества компании соответствует требованиям ГОСТ ISO 9001.

Минимальные сроки поставки, гибкие цены, неограниченный ассортимент и индивидуальный подход к клиентам являются основой для выстраивания долгосрочного и эффективного сотрудничества с предприятиями радиоэлектронной промышленности, предприятиями ВПК и научно-исследовательскими институтами России.

С нами вы становитесь еще успешнее!

Наши контакты:

Телефон: +7 812 627 14 35

Электронная почта: sales@st-electron.ru

Адрес: 198099, Санкт-Петербург,
Промышленная ул, дом № 19, литера Н,
помещение 100-Н Офис 331